N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY			
V_{DS} (V)	$R_{DS(on)}$ (mΩ)(Typ.)	I_D (A)[a]	Q_g (Typ.)
30	3.6 at V_{GS} = 10 V	85	34.5 nC
	5.5 at V_{GS} = 4.5 V		

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- High Current Capability
- RoHS and Halogen-Free Compliant

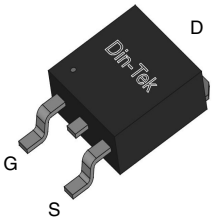
RoHS COMPLIANT

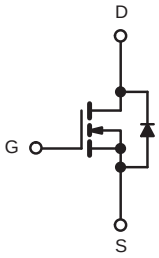
APPLICATIONS

- DC/DC Converters in Computing
- Isolated DC/DC Converters in Telecom and Industrial

TO-252 Pin Configuration

Top View





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (T_J = 150 °C)[a]	T_C = 25 °C	I_D	85	A
	T_C = 100 °C		63	
Pulsed Drain Current[b]		I_{DM}	340	
Single Avalanche Energy		E_{AS}	160	mJ
Maximum Power Dissipation[c]	T_C = 25 °C	P_D	68	W
	T_C = 100 °C		21.2	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to + 150	°C

THERMAL RESISTANCE RATINGS			
PARAMETER	**SYMBOL**	**LIMIT**	**UNIT**
Junction-to-Ambient (PCB Mount)[d]	R_{thJA}	50	°C/W
Junction-to-Case (Drain)	R_{thJC}	1.84	

Notes

a. Calculated continuous current based on maximum allowablejunction temperature.
b. Repetitive rating; pulse width limited by max. junction temperature.
c. Pd is based on max. junction temperature, using junction-case thermal resistance.
d. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.

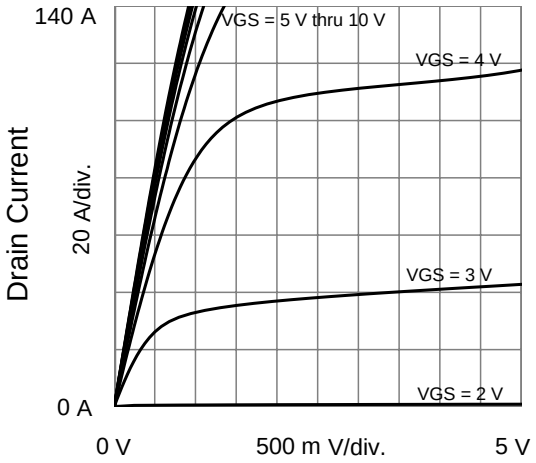
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1	-	3	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55 °C	-	-	10	
On-State Drain Current [a]	$I_{D(on)}$	V_{DS} ≥ 5 V, V_{GS} = 10 V	85	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 20 A	-	3.6	4.5	mΩ
		V_{GS} = 4.5 V, I_D = 15 A	-	5.5	7.2	
Forward Transconductance [a]	g_{fs}	V_{DS} = 5 V, I_D = 20 A	-	45	-	S
Dynamic [b]						
Input Capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 15 V, f = 1 MHz	-	1750	-	pF
Output Capacitance	C_{oss}		-	188	-	
Reverse Transfer Capacitance	C_{rss}		-	173	-	
Total Gate Charge [c]	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 20 A	-	34.5	-	nC
Gate-Source Charge [c]	Q_{gs}		-	2.8	-	
Gate-Drain Charge [c]	Q_{gd}		-	5.6	-	
Gate Resistance	R_g	f = 1 MHz	-	2.8	-	Ω
Turn-On Delay Time [c]	$t_{d(on)}$	V_{DD} = 15 V, I_D = 20 A, R_g = 3 Ω, V_{GS} = 10 V , R_L = 1 Ω	-	7.5	-	ns
Rise Time [c]	t_r		-	12	-	
Turn-Off Delay Time [c]	$t_{d(off)}$		-	30	-	
Fall Time [c]	t_f		-	9.5	-	
Drain-Source Body Diode Ratings and Characteristics [b] (T_C = 25 °C)						
Continuous Source-Drain Diode Current	I_S	T_C = 25 °C	-	-	85	A
Pulsed Current	I_{SM}		-	-	340	A
Forward Voltage [a]	V_{SD}	I_F = 1 A, V_{GS} = 0 V	-	-	1.2	V
Reverse Recovery Time	t_{rr}	I_F = 20 A, di/dt = 100 A/µs	-	11	-	ns
Reverse Recovery Charge	Q_{rr}		-	15	-	nC

Notes

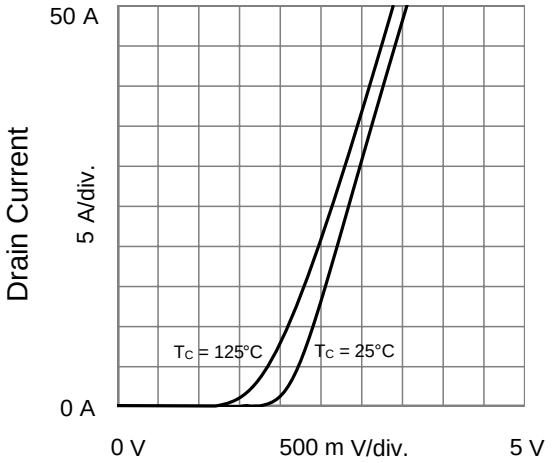
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

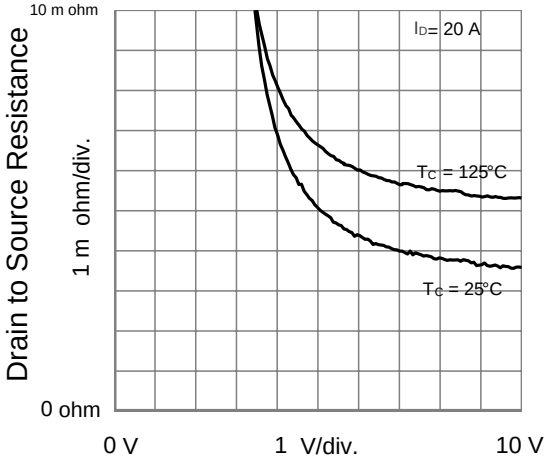
TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)



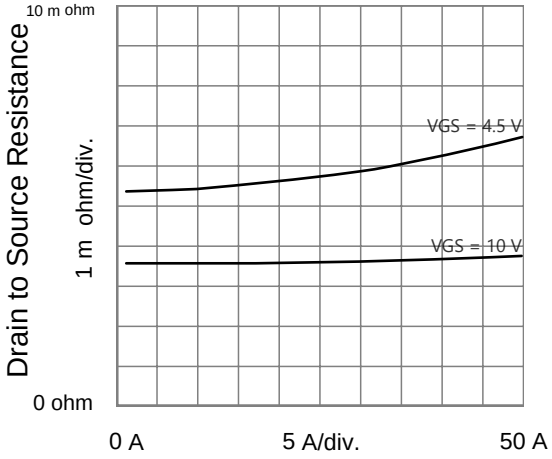
Drain to Source Voltage
Output Characteristics



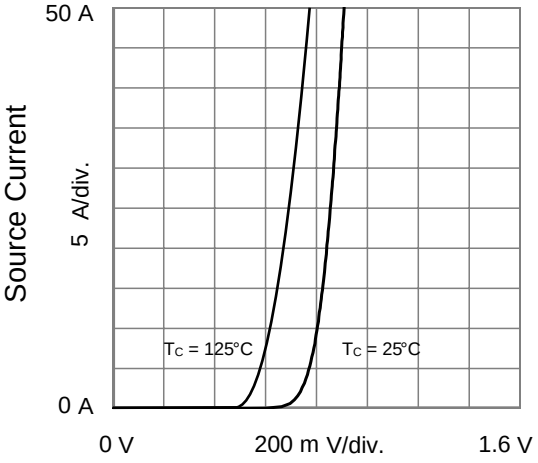
Gate to Source Voltage
Transfer Characteristics



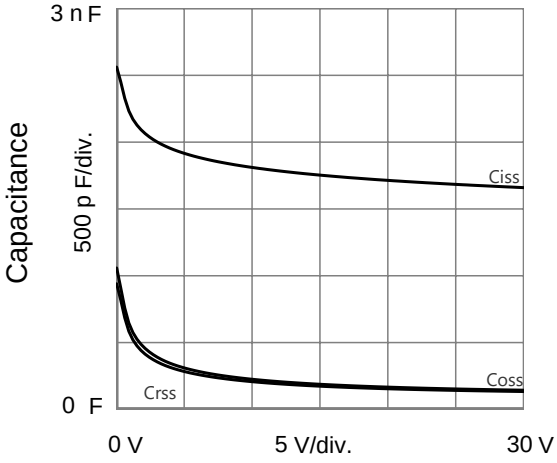
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltag



Drain Current

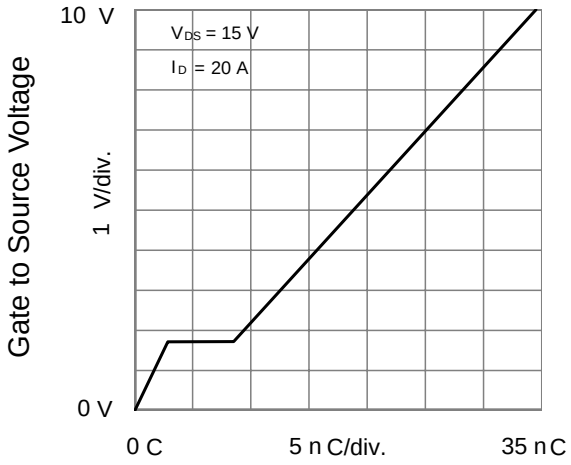


Source to Drain Voltage
Body Diode Forward Characteristics

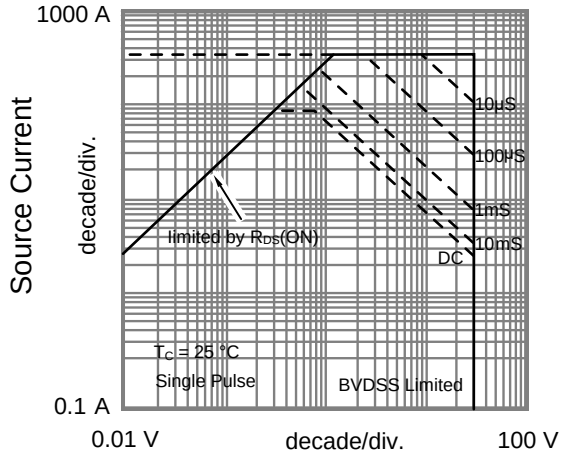


Drain to Source Voltage
Capacitances

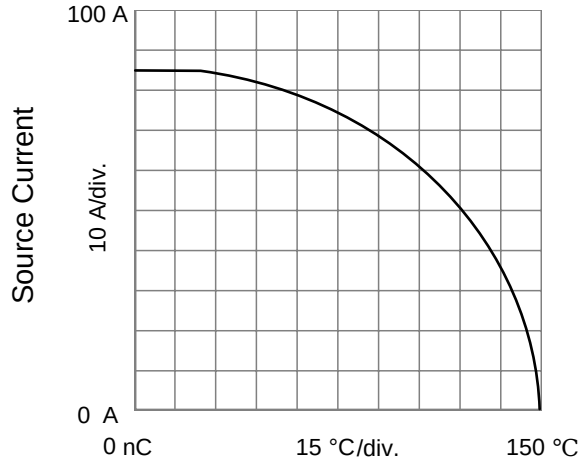
TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)

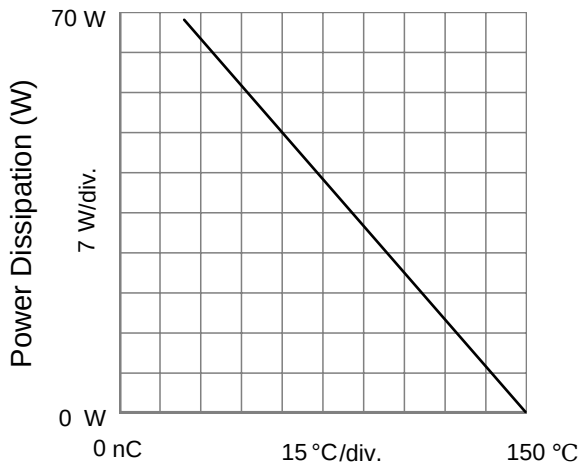


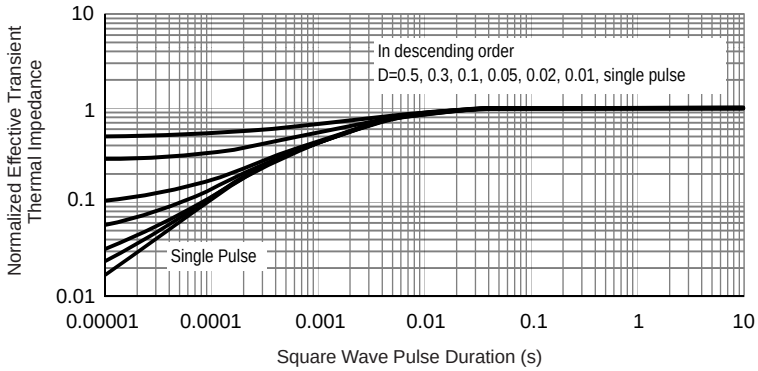
Gate to Source Voltage vs. GateCharge



Safe Operating Area, Junction-to-Case

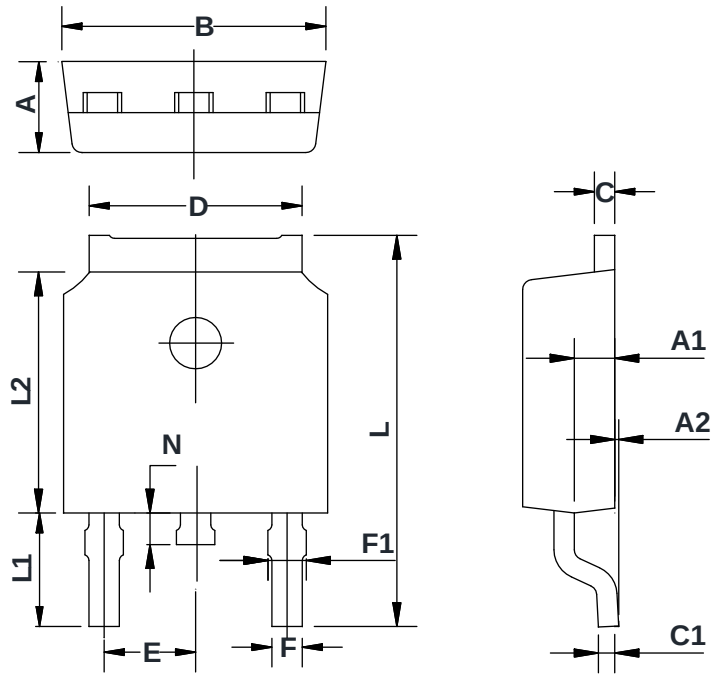






Normalized Thermal Transient Impedance, Junction-to-Case

TO-252–2L PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEA SURE=MILLIMETER)

Symbol	Min	Typ	Max
A	2.10	2.30	2.50
A1	0.88	1.01	1.16
A2	0.00	0.15	0.28
B	6.40	6.60	6.80
C	0.42	0.50	0.63
C1	0.42	0.50	0.63
D	5.08	5.32	5.65
E	2.286 TYP		
F	0.63	0.76	0.89
F1	0.64	0.86	1.08
L	9.30	9.90	10.80
L1	2.40	2.80	3.60
L2	5.90	6.10	6.55
N	0.57	0.80	1.05

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